

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[Diodes Incorporated](#)
[DMP1245UFCL-7](#)

For any questions, you can email us directly:
sales@integrated-circuit.com



DMP1245UFCL

12V P-CHANNEL ENHANCEMENT MODE MOSFET

Summary

V _{(BR)DSS}	R _{DS(on)} max	I _D max
-12V	29mΩ @V _{GS} = -4.5V	-6.6 A
	45mΩ @V _{GS} = -2.5V	-5.3 A
	60mΩ @V _{GS} = -1.8V	-4.6 A
	100mΩ @V _{GS} = -1.5V	-3.5 A

Features and Benefits

- Typical off board profile of 0.5mm ideally suited for thin applications
- Low R_{DS(ON)} minimizes conduction losses
- PCB footprint of 2.56mm²
- **3kV ESD Protected Gate – protection against human borne ESD**
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. “Green” Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

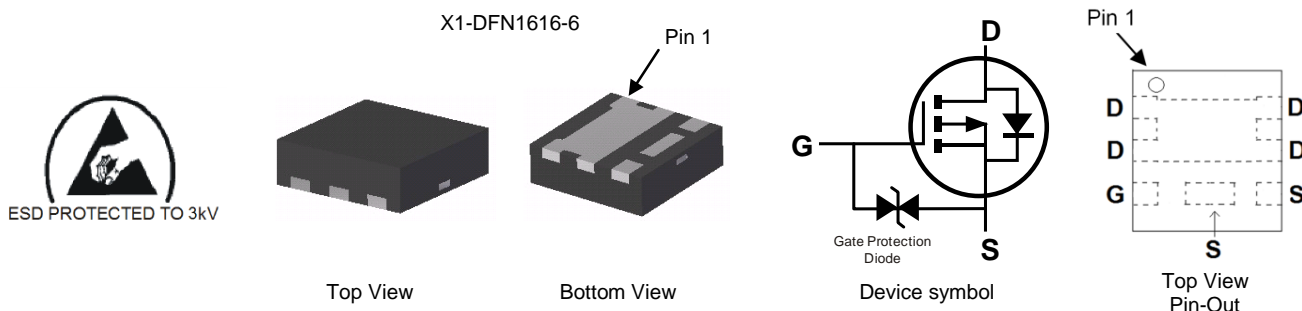
Applications

This device provides high performance, low R_{DS(ON)} P Channel MOSFETs in the thermally and space efficient X1-DFN1616-6 package. The low R_{DS(ON)} of this MOSFET ensures conduction losses are kept making it ideal for use as a:

- Battery Disconnect Switch
- Load Switch for Power Management Functions

Mechanical Data

- Case: X1-DFN1616-6
- Case Material: Molded Plastic, “Green” Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Lead Free Plating (NiPdAu Finish over Copper Leadframe)
- Terminals: Solderable per MIL-STD-202, Method 208 Ⓔ4
- Weight: 0.04 grams (Approximate)



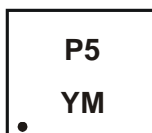
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMP1245UFCL-7	P5	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated’s definitions of Halogen- and Antimony-free, “Green” and Lead-free.
 3. Halogen- and Antimony-free “Green” products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

X1-DFN1616-6



P5 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: Y = 2011)
 M = Month (ex: 9 = September)

Date Code Key

Year Code	2011	2014	2015	2016	2017	2018	2019	2020	2021
Code	Y	B	C	D	E	F	G	H	I

Month Code	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D



DMP1245UFCL

Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	-12	V
Gate-Source Voltage	V _{GSS}	±8	V
Continuous Drain Current (Note 6)	I _D	-6.6 @T _A = +70°C -5.25	A
Pulsed Drain Current	I _{DM}	-16.67	A

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation	P _D	613	mW
		1.7	W
Thermal Resistance, Junction to Ambient	R _{θJA}	204	°C/W
		74	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
- For a device surface mounted on minimum recommended pad layout, in still air conditions; the device is measured when operating in a steady state condition.
 - For a device surface mounted on 25mm by 25mm by 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady state condition.

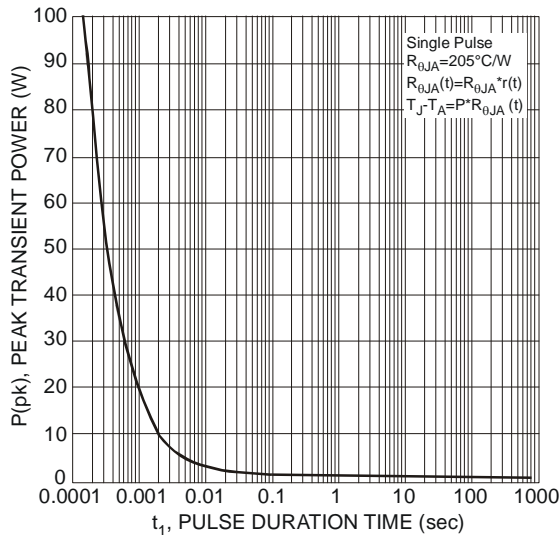


Fig. 1 Single Pulse Maximum Power Dissipation

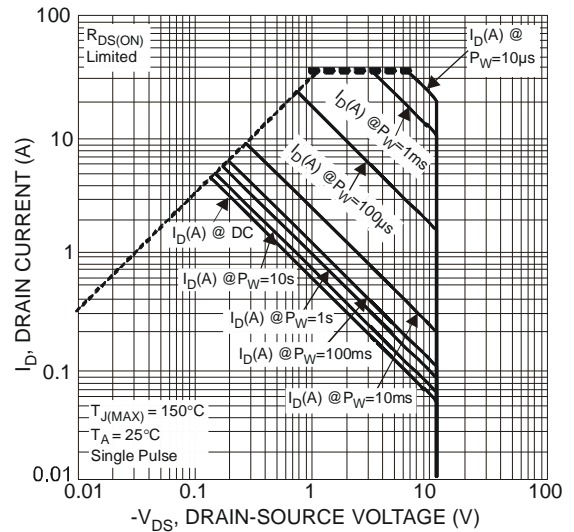


Fig. 2 SOA, Safe Operation Area

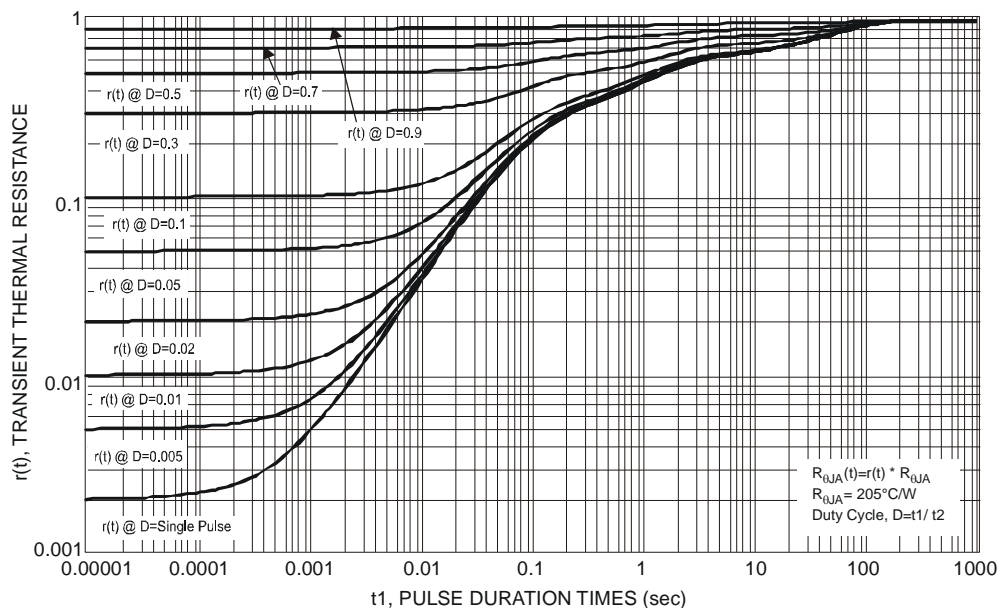


Fig. 03 Transient Thermal Resistance

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$ unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	-12	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current $T_J = +25^\circ\text{C}$	I_{DSS}	—	—	-1	μA	$V_{DS} = -12.0V, V_{GS} = 0V$
Gate-Source Leakage	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 8.0V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(th)}$	-0.3	-0.6	-0.95	V	$V_{DS} = V_{GS}, I_D = -250\mu A$
Static Drain-Source On-Resistance	$R_{DS(on)}$	—	25	29	m Ω	$V_{GS} = -4.5V, I_D = -4A$
		—	31	45		$V_{GS} = -2.5V, I_D = -3.5A$
		—	40	60		$V_{GS} = -1.8V, I_D = -1A$
		—	60	100		$V_{GS} = -1.5V, I_D = -0.5A$
Forward Transfer Admittance	$ Y_{fs} $	0.4	3	-	S	$V_{DS} = -5V, I_D = -2A$
Diode Forward Voltage	V_{SD}	-	-	-1.0	V	$V_{GS} = 0V, I_D = -2A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C_{iss}	-	1357.4	-	pF	$V_{DS} = -10V, V_{GS} = 0V$ $f = 1.0MHz$
Output Capacitance	C_{oss}	-	499	-	pF	
Reverse Transfer Capacitance	C_{rss}	-	273.6	-	pF	
Gate Resistance	R_g	-	14.26	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Q_g	-	16.1	-	nC	$V_{GS} = -4.5V$ $I_D = -1A,$ $V_{DS} = -10V$
Gate-Source Charge		Q_{gs}	-	1.71	-	
Gate-Drain Charge	Q_{gd}	-	20.48	-	nC	
Turn-On Delay Time	$t_{D(on)}$	-	15.2	-	ns	
Turn-On Rise Time	t_r	-	33.11	-	ns	$V_{GS} = -2.5V, V_{DS} = -10V$ $I_D = -180mA, R_G = 2.0\Omega,$
Turn-Off Delay Time	$t_{D(off)}$	-	219.4	-	ns	
Turn-Off Fall Time	t_f	-	217.64	-	ns	

Notes: 7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.



DMP1245UFCL

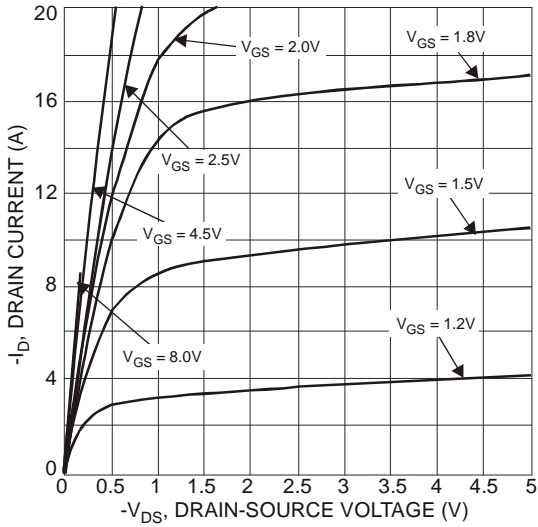


Fig. 4 Typical Output Characteristics

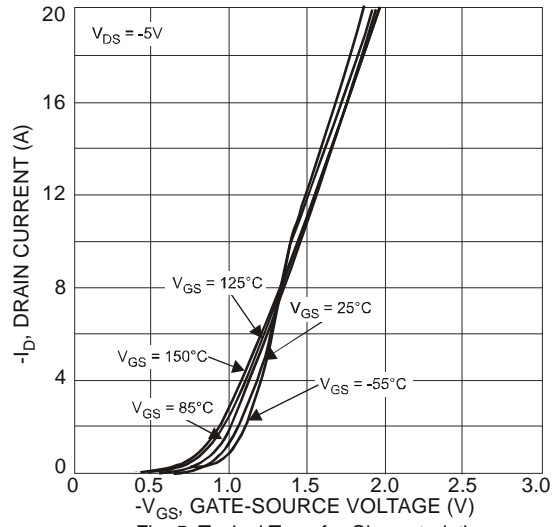


Fig. 5 Typical Transfer Characteristic

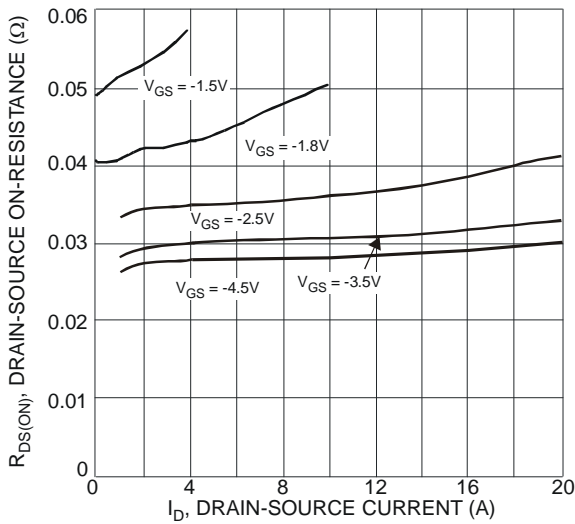


Fig. 6 Typical On-Resistance vs. Drain Current and Gate Voltage

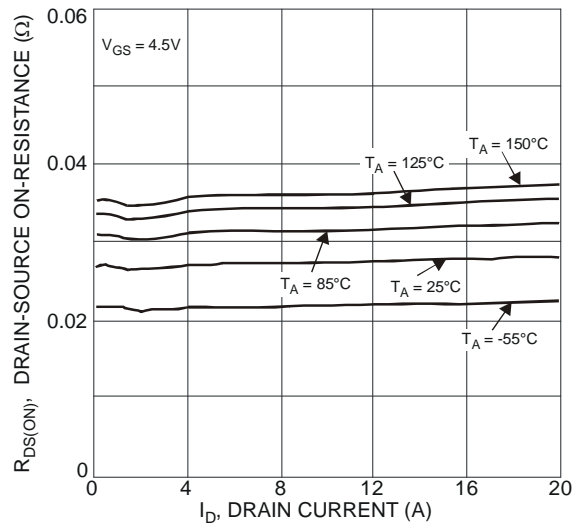


Fig. 7 Typical On-Resistance vs. Drain Current and Temperature

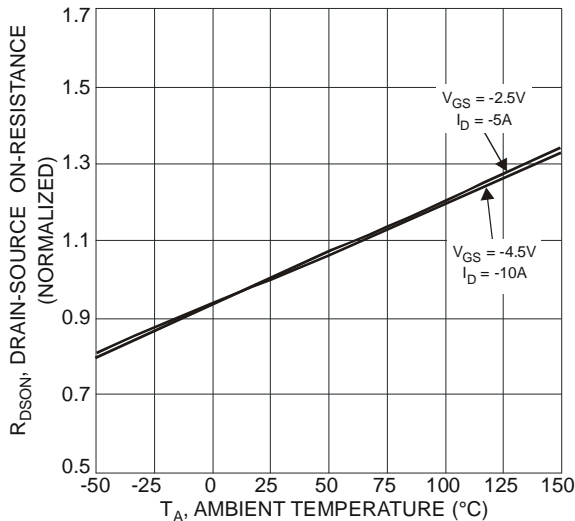


Fig. 8 On-Resistance Variation with Temperature

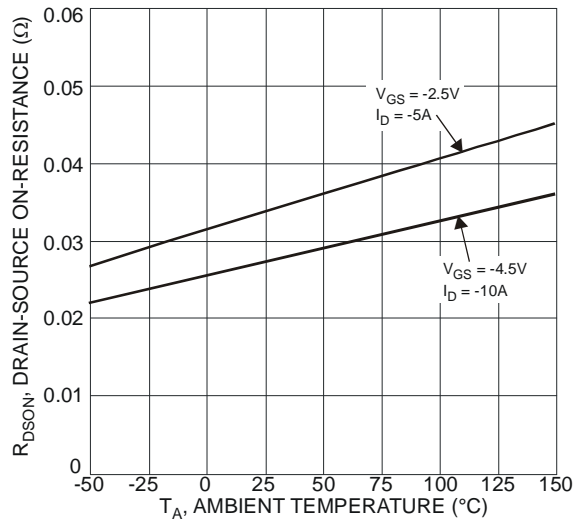


Fig. 9 On-Resistance Variation with Temperature



DMP1245UFCL

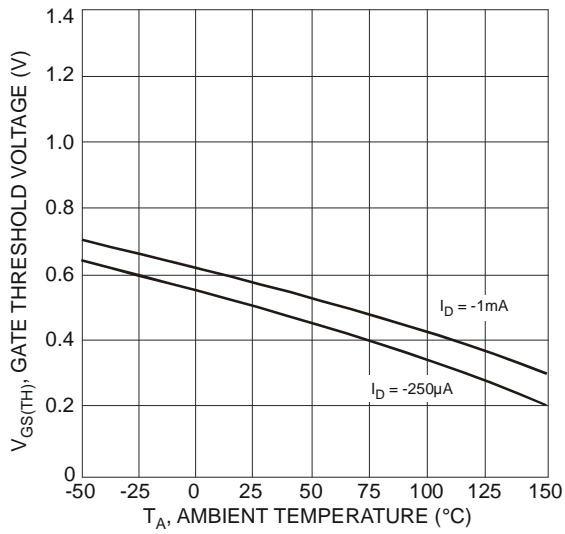


Fig. 10 Gate Threshold Variation vs. Ambient Temperature

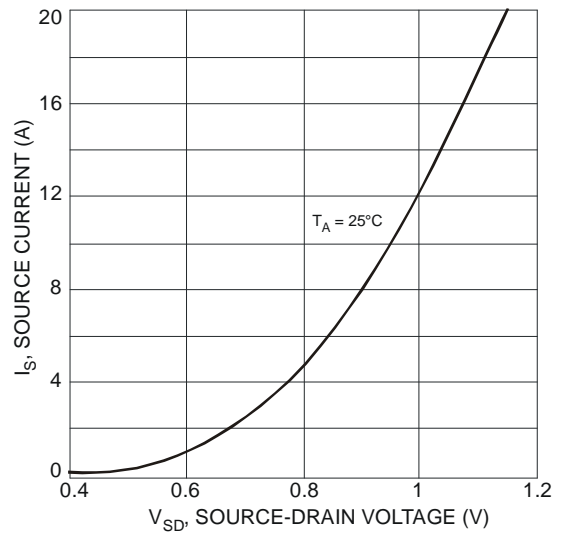


Fig. 11 Diode Forward Voltage vs. Current

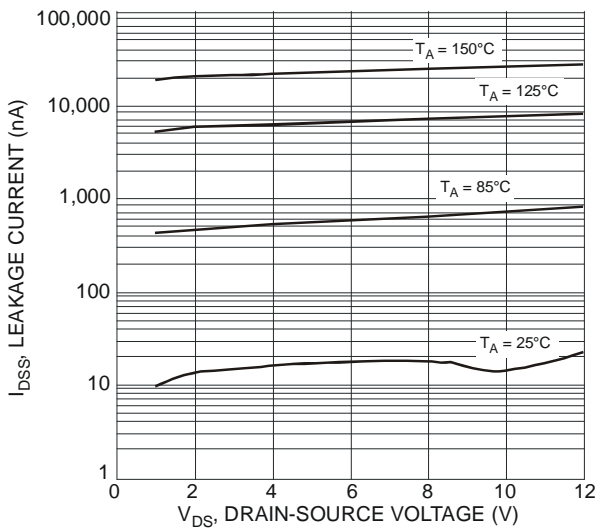


Fig. 12 Typical Drain-Source Leakage Current vs. Voltage

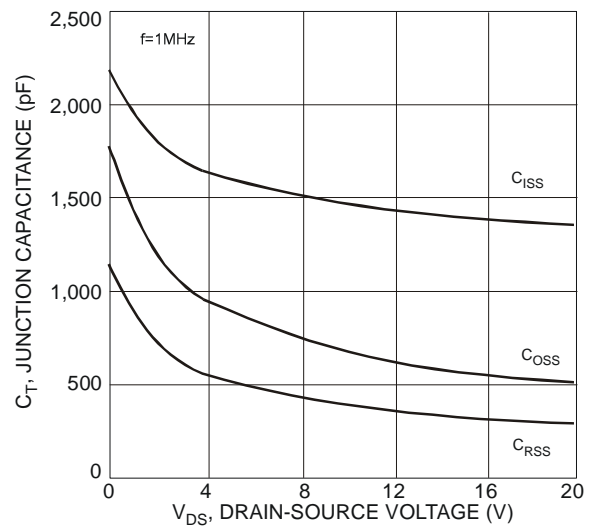


Fig. 13 Typical Junction Capacitance

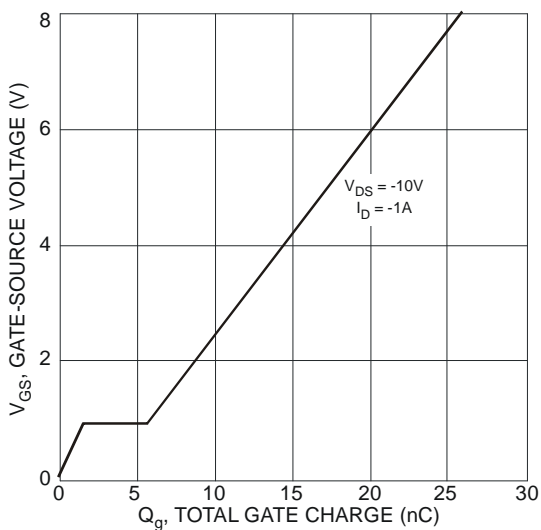
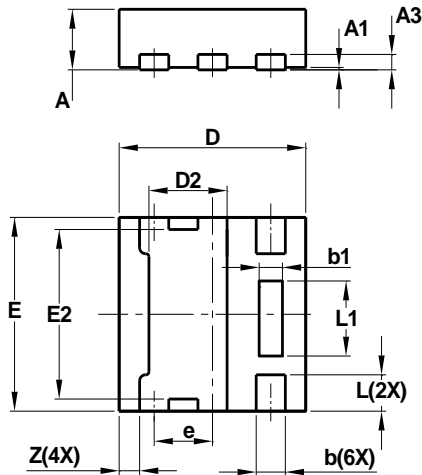


Fig. 14 Gate-Charge Characteristics

Package Outline Dimensions

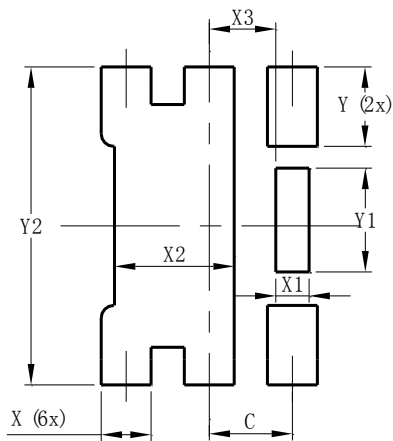
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



X1-DFN1616-6 Type E			
Dim	Min	Max	Typ
A	0.47	0.53	0.50
A1	0	0.05	0.02
A3	—	—	0.13
b	0.20	0.30	0.25
b1	0.10	0.30	0.20
D	1.55	1.65	1.60
D2	0.57	0.77	0.67
E	1.55	1.65	1.60
E2	1.30	1.50	1.40
e	—	—	0.50
L	0.25	0.35	0.30
L1	0.52	0.72	0.62
Z	—	—	0.175
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for latest version.



Dimensions	Value (in mm)
C	0.500
X	0.300
X1	0.200
X2	0.720
X3	0.400
Y	0.475
Y1	0.620
Y2	1.900

**DMP1245UFCL****IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com